

REMARKS

Claims 40, 60, 77, 94 - 98, 167, and 182 have been amended in several generally minor respects. No claims have been added or canceled. Accordingly, Claims 1 - 265 remain pending.

Please telephone Applicants' attorney at 408-453-9200, ext. 1371, if there are any questions.

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Respectfully submitted,

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APPENDIX

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CLAIMS 40, 60, 77,94 - 98, 167 AND 182,

WITH ANNOTATIONS TO INDICATE REVISIONS,

OF U.S. PATENT APPLICATION 09/698,696

40. (Amended) A structure as in Claim 39 wherein the electron-emitting device includes a getter region situated at least partially in an active electron-emitting portion of the electron-emitting device.

60. (Amended) A structure as in Claim 59 wherein the light-emitting device includes a getter region situated at least partially in an active light-emitting portion of the light-emitting device.

77. (Amended) A structure as in Claim 76 wherein the light-emitting device includes a getter region situated at least partially in an active light-emitting portion of the light-emitting device.

94. (Amended) A structure as in Claim 84 [78] further including a device for emitting light upon being struck by electrons emitted by the electron-emissive [emissive] elements.

95. (Amended) A structure as in Claim 94 wherein the light-emitting device includes a getter region situated at least partially in an active light-emitting portion of the light-emitting device.

96. (Amended) A structure as in Claim 84 [78] wherein the getter region comprises at least one of aluminum, titanium, vanadium, iron, zirconium, niobium, molybdenum, barium, tantalum, tungsten, and thorium.

97. (Amended) A structure as in Claim 84 [78] wherein the getter region consists largely of only a single atomic element.

98. (Amended) A structure as in Claim 84 [78] wherein the single atomic element is one of aluminum, titanium, vanadium, iron, zirconium, niobium, molybdenum, barium, tantalum, tungsten, and thorium.

167. (Amended) A method as in Claim 166 further including the step of applying a selected electrical potential to the non-insulating layer.

182. (Amended) A method as in Claim 181 further including the [a] step of providing electrically insulating material over at least part of the control electrode.